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Kind regards,

Team Nexperia

NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

Rev. 5 — 16 December 2011

**Product data sheet** 

#### 1. Product profile

#### 1.1 General description

NPN/NPN double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1.	Product	overview
14010 11		01011011

Type number	Package	5			Package
	NXP	JEITA	complement	complement	configuration
PEMH15	SOT666	-	PEMD15	PEMB15	ultra small and flat lead
PUMH15	SOT363	SC-88	PUMD15	PUMB15	very small

Reduces component count

AEC-Q101 qualified

Reduces pick and place costs

#### **1.2 Features and benefits**

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- 1.3 Applications
  - Low current peripheral driver
  - Control of IC inputs
  - Replaces general-purpose transistors in digital applications

#### 1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>O</sub>	output current		-	-	100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



#### NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

#### 2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	GND (emitter) TR1		
2	input (base) TR1		
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

#### 3. Ordering information

Table 4. Ord	ering inforn	nation	
Type number	Package		
	Name	Description	Version
PEMH15	-	plastic surface-mounted package; 6 leads	SOT666
PUMH15	SC-88	plastic surface-mounted package; 6 leads	SOT363

#### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
PEMH15	5F
PUMH15	H2*

[1] \* = placeholder for manufacturing site code

| | 2 3 *sym063* 

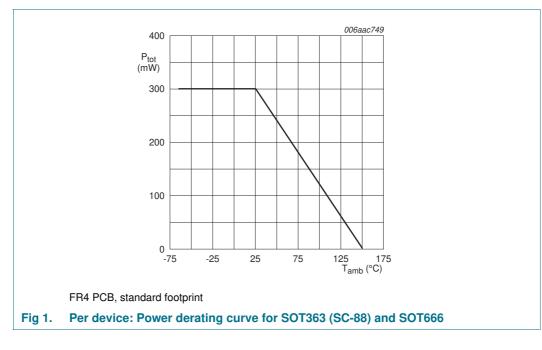
#### 5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+30	V
	negative		-	-10	V
lo	output current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMH15 (SOT666)		<u>[1][2]</u> _	200	mW
	PUMH15 (SOT363)		[1] -	200	mW
Per device	)				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMH15 (SOT666)		<u>[1][2]</u> _	300	mW
	PUMH15 (SOT363)		[1] -	300	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 



#### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	PEMH15 (SOT666)		<u>[1][2]</u> _	-	625	K/W
	PUMH15 (SOT363)		<u>[1]</u> _	-	625	K/W
Per devic	e					
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	PEMH15 (SOT666)		<u>[1][2]</u> _	-	417	K/W
	PUMH15 (SOT363)		<u>[1]</u> -	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

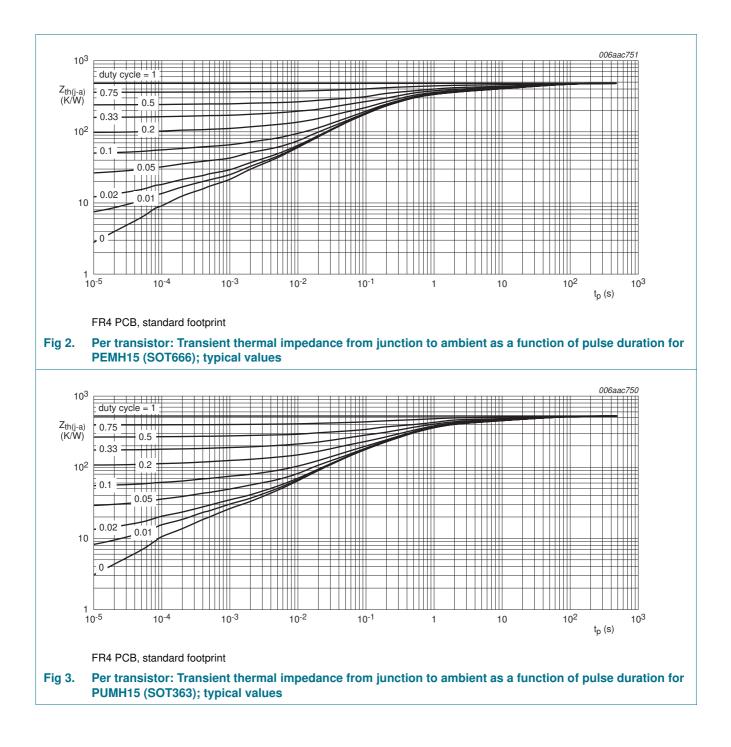
[2] Reflow soldering is the only recommended soldering method.

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PEMH15\_PUMH15 Product data sheet

## PEMH15; PUMH15

NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 



#### 7. Characteristics

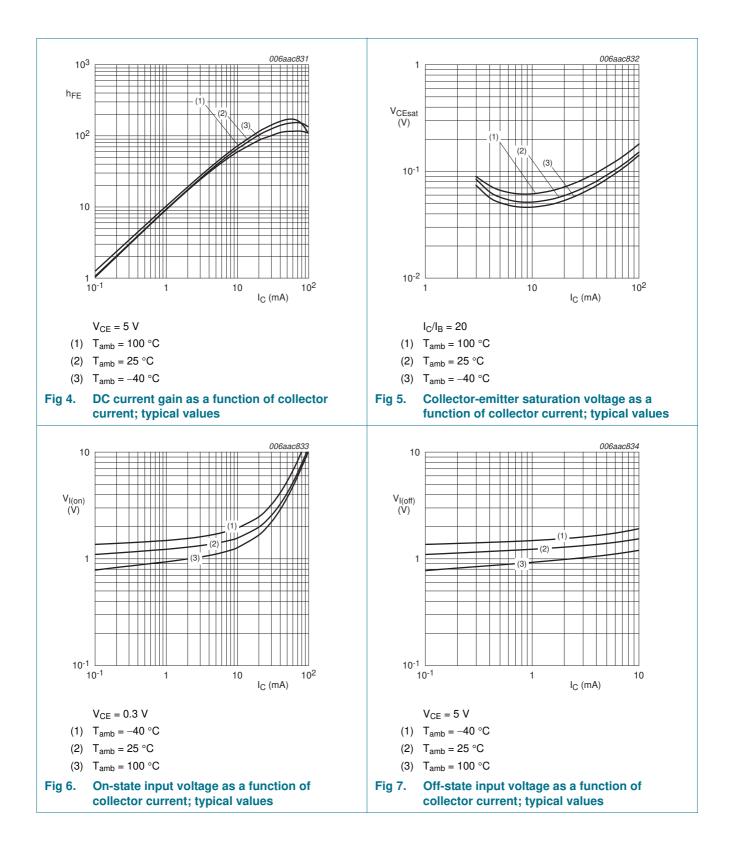
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor					
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$	-	-	1	μA
current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	5	μA	
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	900	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$	-	-	150	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}=5~V;~I_{C}=100~\mu A$	-	1.1	0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 20 \text{ mA}$	2.5	1.9	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$	-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_C = 10 \text{ mA};$ f = 100 MHz	<u>1]</u> _	230	-	MHz

[1] Characteristics of built-in transistor

PEMH15\_PUMH15 Product data sheet

## PEMH15; PUMH15

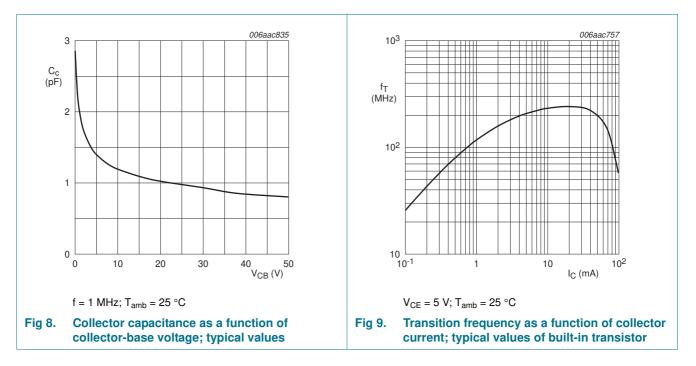
#### NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$



PEMH15 PUMH15

## PEMH15; PUMH15

NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

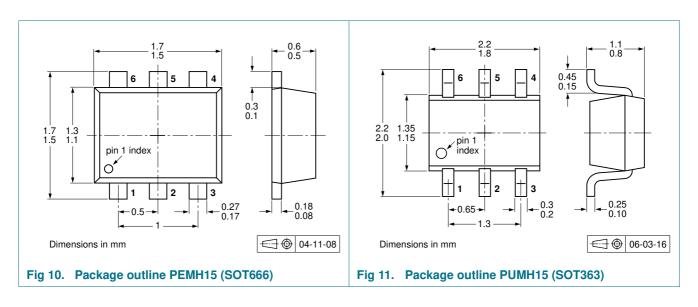


#### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### 9. Package outline



PEMH15\_PUMH15

#### **10. Packing information**

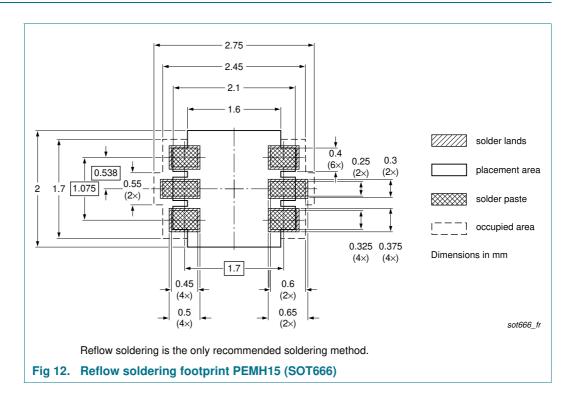
#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

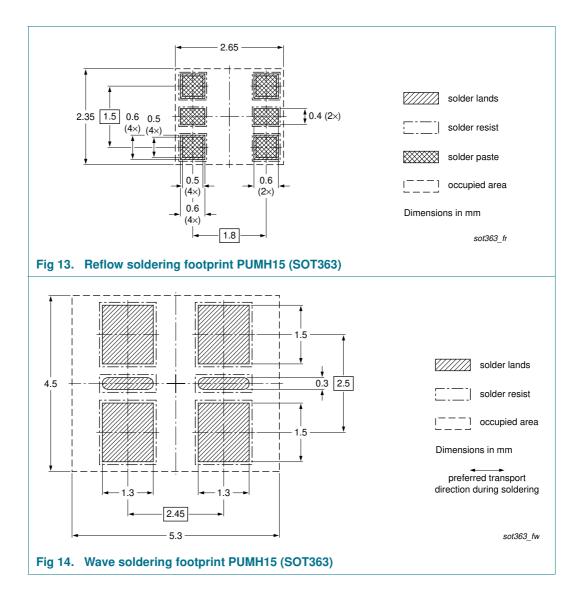
Туре	Package	Description		Packin	g quant	ity	
number					4000	8000	10000
PEMH15	SOT666	2 mm pitch, 8 mm tape and reel		-	-	-315	-
		4 mm pitch, 8 mm tape and reel		-	-115	-	-
PUMH15	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-	-	-165

- [1] For further information and the availability of packing methods, see Section 14.
- [2] T1: normal taping
- [3] T2: reverse taping

#### 11. Soldering



NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 



PEMH15\_PUMH15 Product data sheet

#### 12. Revision history

#### Table 10.Revision history

	-					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
PEMH15_PUMH15 v.5	20111216	Product data sheet	-	PEMH15_PUMH15 v.4		
Modifications:	<ul> <li>Section 1 "P</li> </ul>	roduct profile": updated				
	<u>Section 4 "Marking"</u> : updated					
	<ul> <li>Figure 1 to 3, 8 and 9: added</li> </ul>					
	• Figure 4 to 7: updated					
	<u>Section 5 "Limiting values"</u> : updated					
	<u>Section 6 "Thermal characteristics"</u> : updated					
	<ul> <li><u>Table 8 "Characteristics</u>": V<sub>i(on)</sub> redefined to V<sub>I(on)</sub> on-state input voltage, V<sub>i(off)</sub> redefined to V<sub>I(off)</sub> off-state input voltage, I<sub>CEO</sub> updated, f<sub>T</sub> added</li> </ul>					
	<u>Section 8 "Test information"</u> : added					
	<u>Section 11 "Soldering"</u> : added					
	<ul> <li>Section 13 "</li> </ul>	Legal information": update	d			
PEMH15_PUMH15 v.4	20091115	Product data sheet	-	PEMH15_PUMH15 v.3		
PEMH15_PUMH15 v.3	20050211	Product data sheet	-	PUMH15 v.2		
PUMH15 v.2	20040414	Product specification	-	PUMH15 v.1		
PUMH15 v.1	20031009	Product specification	-	-		

#### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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PEMH15\_PUMH15

#### NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

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#### PEMH15\_PUMH15 Product data sheet

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## PEMH15; PUMH15

NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$ 

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Date of release: 16 December 2011 Document identifier: PEMH15\_PUMH15